





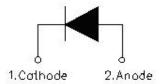
SDUR60Q80W ULTRAFAST RECTIFIER



Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification 94V-O
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	800	V
Average Rectified Forward Current	I _{F (AV)}	Tc=126°C, In DC	60	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	400	А

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	ΤJ	-	-55 to +175	°C
Storage Temperature	T_{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R ₀ JC	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

- China Germany Korea Singapore United States •
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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 30A, Pulse, T _J = 25°C @ 60A, Pulse, T _J = 25°C	1.74 2.06	- 2.4	V
	V_{F2}	@ 30A, Pulse, T _J = 125°C @ 60A, Pulse, T _J = 125°C	1.43 1.80	- 2.0	V
	V _{F3}	@ 30A, Pulse, T _J = 150°C @ 60A, Pulse, T _J = 150°C	1.34 1.70	-	٧
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J =25°C	0.02	25	uA
	I _{R2}	@V _R = rated V _R , T _J =125°C	21	500	uA
	I _{R3}	@V _R = rated V _R , T _J =150°C	90	-	uA
Reverse Recovery Time	t _{rr1}	I _F =500mA,I _R =1A,and I _m =250mA,T _J =25°C	46	60	ns
Reverse Recovery Time	t _{rr}		218	-	ns
Reverse Recovery Charge	Qrr	l _F = 30A, dif/dt = -200A/µs VR = 300V, T _J = 25°C	610	-	nC
Reverse Recovery Current	I _{RRM}	VK = 500V, 13 = 25 C	5.6	-	Α
Reverse Recovery Time	t _{rr}		293	-	ns
Reverse Recovery Charge	Q _{rr}	l l _F = 30A, dir/dt = -200A/µs l VR = 300V, T _J = 125°C	1639	-	nC
Reverse Recovery Current	I _{RRM}	VK = 300V, 1j = 123 C	11.2	-	Α
Reverse Recovery Time	t _{rr}		37.3	-	ns
Reverse Recovery Charge	Qrr	l l _F = 1A, diF/dt = -100A/μs VR = 30V, T _J = 25°C	45	-	nC
Reverse Recovery Current	I _{RRM}	7 VIX - 30 V, 13 - 20 O	2.4	-	Α

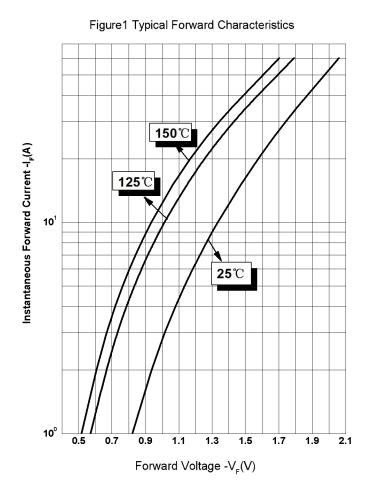
^{*} Pulse width < 300 μ s, duty cycle < 2%

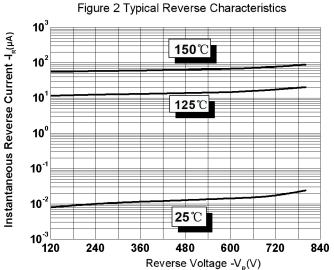


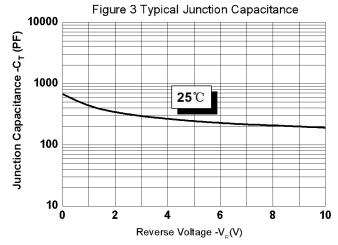




Ratings and Characteristics Curves







[•] China - Germany - Korea - Singapore - United States •

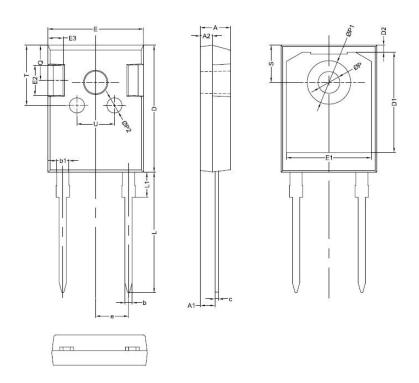
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Mechanical Dimensions TO-247AC

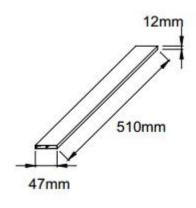


CVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.35	
b1	1.80	2.00	2.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.58		
D2		1.17		
Е	15.60	15.80	16.00	
E1		14.02		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.42	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1	7.19	7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

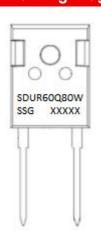
Ordering Information

Device	Package	Plating	Shipping	
SDUR60Q80W	TO-247AC(Pb-Free)	Pure Sn	25pcs / tube	

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type 60 = Forward Current (60A) Q = Q

80 = Reverse Voltage (800V) W = Configuration

SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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SDUR60Q80W



Technical Data Data Sheet N2733, Rev.A





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